PEMB9; PUMB9

PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 47 k Ω

Rev. 3 — 22 November 2011

Product data sheet

1. Product profile

1.1 General description

PNP/PNP double Resistor-Equipped Transistors (RET) in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number				NPN/NPN	Package	
	NXP	JEITA	complement	complement	configuration	
PEMB9	SOT666	-	PEMD9	РЕМН9	ultra small and flat lead	
PUMB9	SOT363	SC-88	PUMD9	PUMH9	very small	

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	or					
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
Io	output current		-	-	-100	mA
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		3.7	4.7	5.7	



2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	GND (emitter) TR1	· 	. ,
2	input (base) TR1	6 5 4	6 5 4
3	output (collector) TR2		
4	GND (emitter) TR2		
5	input (base) TR2		TR1
6	output (collector) TR1	001aab555	R2 R1
			1 2 3
			006aaa212

3. Ordering information

Table 4. Ordering information

Type number	Package	ackage			
	Name	Description	Version		
PEMB9	-	plastic surface-mounted package; 6 leads	SOT666		
PUMB9	SC-88	plastic surface-mounted package; 6 leads	SOT363		

4. Marking

Table 5. Marking codes

Type number	Marking code ^[1]
PEMB9	Z6
PUMB9	B*9

[1] * = placeholder for manufacturing site code

5. Limiting values

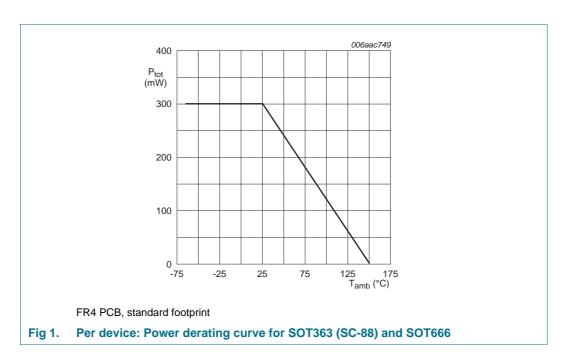
Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor				
V_{CBO}	collector-base voltage	open emitter	-	-50	V
V_{CEO}	collector-emitter voltage	open base	-	-50	V
V_{EBO}	emitter-base voltage	open collector	-	-6	V
V_{I}	input voltage				
	positive		-	+6	V
	negative		-	-40	V
Io	output current		-	-100	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	PEMB9 (SOT666)		[1][2] _	200	mW
	PUMB9 (SOT363)		<u>[1]</u> -	200	mW
Per device)				
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	PEMB9 (SOT666)		[1][2] _	300	mW
	PUMB9 (SOT363)		<u>[1]</u> -	300	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.



6. Thermal characteristics

Table 7. Thermal characteristics

Parameter	Conditions	onditions Min		Max	Unit
Per transistor					
thermal resistance from junction to ambient	in free air				
PEMB9 (SOT666)		[1][2]	-	625	K/W
PUMB9 (SOT363)		<u>[1]</u> _	-	625	K/W
thermal resistance from junction to ambient	in free air				
PEMB9 (SOT666)		[1][2] _	-	417	K/W
PUMB9 (SOT363)		<u>[1]</u> -	-	417	K/W
	thermal resistance from junction to ambient PEMB9 (SOT666) PUMB9 (SOT363) thermal resistance from junction to ambient PEMB9 (SOT666)	thermal resistance from in free air junction to ambient PEMB9 (SOT666) PUMB9 (SOT363) thermal resistance from in free air junction to ambient PEMB9 (SOT666)	thermal resistance from in free air junction to ambient PEMB9 (SOT666) PUMB9 (SOT363) 11 - thermal resistance from in free air junction to ambient PEMB9 (SOT666) 11 2 -	thermal resistance from in free air junction to ambient PEMB9 (SOT666) PUMB9 (SOT363) [1] thermal resistance from in free air junction to ambient PEMB9 (SOT666) [1][2]	thermal resistance from junction to ambient PEMB9 (SOT666) PUMB9 (SOT363) Ill 625 thermal resistance from junction to ambient PEMB9 (SOT666) Ill 417

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

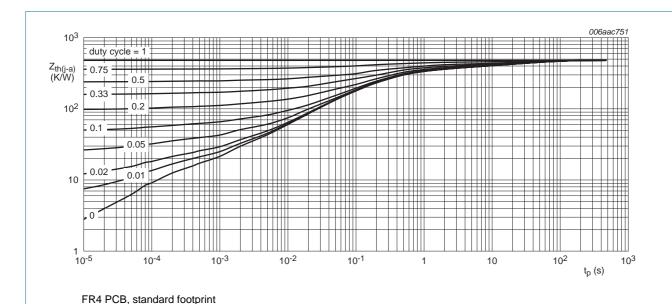


Fig 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration for PEMB9 (SOT666); typical values

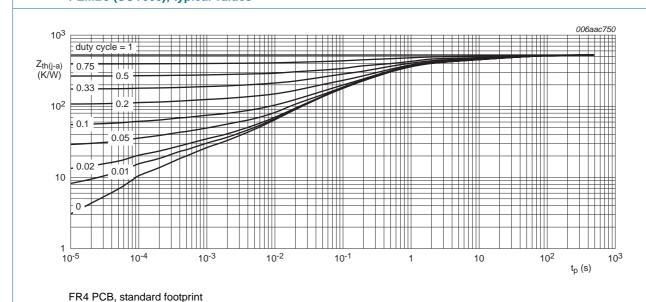


Fig 3. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration for PUMB9 (SOT363); typical values

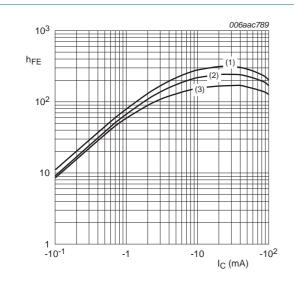
7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	istor					
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I _{CEO}	collector-emitter cut-off	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$	-	-	-1	μΑ
	current	$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-150	μΑ
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -5 \text{ mA}$	100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -5 \text{ mA}; I_B = -0.25 \text{ mA}$	-	-	-100	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = -5 \text{ V}; I_{C} = -100 \mu\text{A}$	-	-0.7	-0.5	V
V _{I(on)}	on-state input voltage	$V_{CE} = -0.3 \text{ V}; I_{C} = -1 \text{ mA}$	-1.4	-0.8	-	V
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		3.7	4.7	5.7	
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA}; $ [1] f = 100 MHz	-	180	-	MHz

^[1] Characteristics of built-in transistor



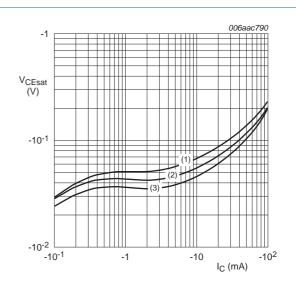
$$V_{CE} = -5 \text{ V}$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig 4. DC current gain as a function of collector current; typical values



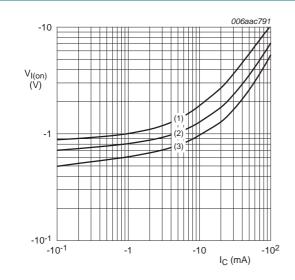
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 5. Collector-emitter saturation voltage as a function of collector current; typical values



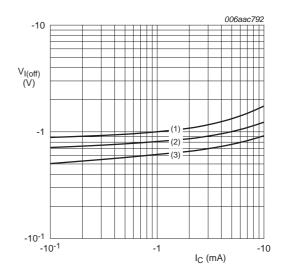
$$V_{CE} = -0.3 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig 6. On-state input voltage as a function of collector current; typical values



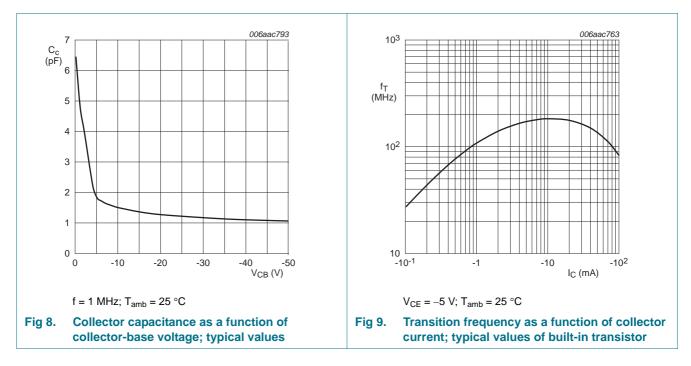
$$V_{CE} = -5 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig 7. Off-state input voltage as a function of collector current; typical values

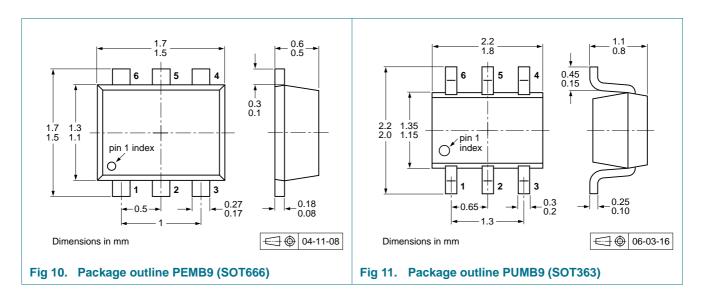


8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



PEMB9_PUMB9

10. Packing information

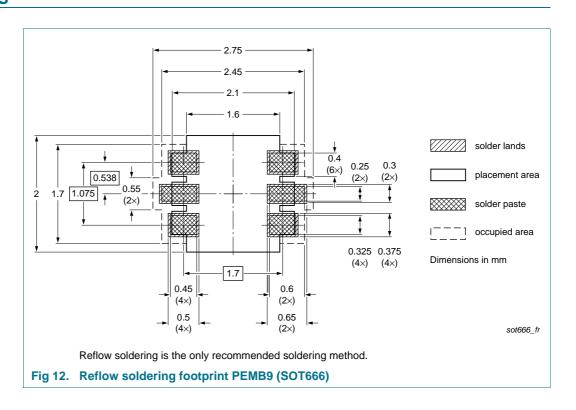
Table 9. Packing methods

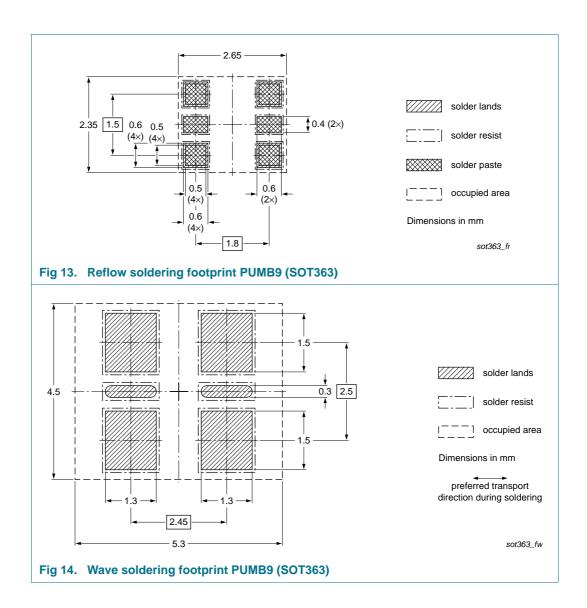
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type Packa number	Package	e Description		Packing quantity				
				4000	8000	10000		
PEMB9 SOT666	2 mm pitch, 8 mm tape and reel	-	-	-315	-			
		4 mm pitch, 8 mm tape and reel	-	-115	-	-		
PUMB9 SOT363	4 mm pitch, 8 mm tape and reel; T1	1 -115	-	-	-135			
		4 mm pitch, 8 mm tape and reel; T2	-125	-	-	-165		

- [1] For further information and the availability of packing methods, see Section 14.
- [2] T1: normal taping
- [3] T2: reverse taping

11. Soldering





12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
			Change Houce	•		
PEMB9_PUMB9 v.3	20111122	Product data sheet	-	PEMB9_PUMB9 v.2		
Modifications:		of this document has been of NXP Semiconductors.	redesigned to comply w	ith the new identity		
	 Legal texts have been adapted to the new company name where appropriate. 					
	Section 1 "Product profile": updated					
	 Section 4 " 	Marking": updated				
• Figure 1 to 9: added						
 <u>Section 5 "Limiting values"</u>: updated 						
	Section 6 "Thermal characteristics": updated					
		naracteristics": V _{i(on)} redefine ate input voltage, I _{CEO} upda		t voltage, V _{i(off)} redefined to		
	Section 8 "Test information": added					
	 Section 9 "Package outline": superseded by minimized package outline drawings 					
	Section 10 "Packing information": added					
	 Section 11 	"Soldering": added				
	Section 13	"Legal information": update	d			
PEMB9_PUMB9 v.2	20031003	Product data sheet	-	PUMB9 v.1 PEMB9 v.1		
PUMB9 v.1	20030203	Objective specification	-	-		
PEMB9 v.1	20030107	Product specification	-	-		

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13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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PEMB9_PUMB9

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PEMB9; PUMB9

PNP/PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = 47 k Ω

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